$50\Omega$ 0.05 to 6 GHz

# **The Big Deal**

- Ultra Low Noise Figure, 0.8 dB
- High IP3/Low Current, 20mA
- Wideband, up to 6 GHz



3mm x 3mm MCLP (EIA: QFN) Pkg

## **Product Overview**

Mini-Circuits PMA-5454+ is a E-PHEMT based Ultra-Low Noise MMIC Amplifier operating from 50 MHz to 6 GHz with a unique combination of low noise and high IP3 making this amplifier ideal for sensitive receiver applications. This design operates on a single 5V supply at only 20mA and is internally matched to 50 Ohms.

## **Key Features**

Feature	Advantages		
Ultra Low Noise, 0.8 dB	Outstanding Noise Figure, measured in a 50 Ohm environment without any external matching		
High IP3, 27 dBm	Combining Low Noise and High IP3 makes this MMIC amplifier ideal for Low Noise Receiver Front End (RFE) because it gives the user advantages at both ends of the dynamic range: sensitivity & two-tone spur-free dynamic range		
Low Current, 20mA	At only 20mA, the PMA-5454+ is ideal for remote applications with limited available power or densely packed applications where thermal management is critical.		
Broad Band	Operating over a broadband the PMA-5454+ covers the primary wireless communications bands Cellular, PCS, LTE, WiMAX		
Internally Matched	No external matching elements required to achieve the advertised noise and output power over full band		
MCLP Package	Low Inductance, repeatable transitions, excellent thermal pad		
Max Input Power, +20 dBm	Ruggedized design operates up to input powers of +20 dBm without the need of an external limite		
High Reliability	Low, small signal operating current of 20mA nominal maintains junction temperatures typically below 100°C at 85°C ground lead temperature		



For detailed performance speci

# **Monolithic Amplifier**

0.05-6 GHz

#### **Product Features**

- Single Positive Supply Voltage, 5V, Id=20mA
- Ultra Low Noise Figure, 0.8 dB typ. at 0.5 GHz
- High IP3, 27 dBm typ. 1GHz
- Gain, 18dB typ. at 1 GHz
- Output Power, up to +15 dBm typ.
- Micro-miniature size -3mm x 3mm
- Aqueous washable

## **Typical Applications**

- Cellular
- ISM
- GSM
- WCDMA
- LTE
- WiMAX
- WLAN
- UNII and HIPERLAN



CASE STYLE: DQ849 PRICE: \$1.49 ea. QTY. (10-49)

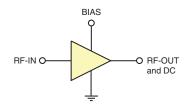
+ RoHS compliant in accordance with EU Directive (2002/95/EC)

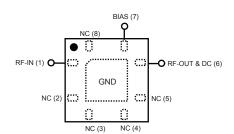
The +Suffix has been added in order to identify RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications.

## **General Description**

PMA-5454+ is a high dynamic range, low noise, high IP3, high output power, monolithic amplifier. Manufactured using E-PHEMT\* technology enables it to work with a single positive supply voltage.

#### simplified schematic and pad description





Function	Pad Number	Description (See Application Circuit, Fig. 3)		
RF-IN	1	RF input pad		
RF-OUT & DC	RF output pad (connected to RF-OUT via blocking external cap of voltage Vs via RF Choke L1)			
BIAS	7	Bias pad (connected to Vs via Rbias)		
GND	GND paddle in center of bottom Connected to ground			
NOT USED 2,3,4,5,8		No internal connection; recommended use: per PCB Layout PL-299		

<sup>\*</sup>Enhancement mode Pseudomorphic High Electron Mobility Transistor.



For detailed performance specs



## Electrical Specifications<sup>(1)</sup> at 25°C, Zo=50 $\Omega$ , (refer to characterization circuit, Fig. 1)

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range		0.05		6.0	GHz
DC Voltage (V <sub>d</sub> )			5.0		V
DC Current (I <sub>d</sub> )		12	20	40	mA
DC Current (I <sub>Rbias</sub> )			0.6		mA
( Tiblias)	0.05		1.7		dB
	0.5		0.8		
	1.0		0.9		
N : - F	2.0		1.0	1.3	
Noise Figure	3.0		1.4		
	4.0		1.8		
	5.0		2.0		
	6.0		2.5		
	0.05		23.6		dB
	0.5		21.7		
	1.0		18.4		
Gain	2.0	12.1	13.5	14.9	
dani	3.0		10.4		
	4.0		8.5		
	5.0		6.6		
	6.0		5.2		
Input Return Loss	0.05-0.5		9.0		dB
input Hetuin 2009	0.5-6		6.0		
Output Detum Less	0.05-0.5		12.0		dB
Output Return Loss	0.5-6		18.0		ub
	0.05		24.6		
	0.5		25.6		
	1.0		26.5		
Output IP3	2.0		28.1		dBm
Output IF 3	3.0		28.8		
	4.0		28.3		
	5.0		29.3		
	6.0		29.8		
	0.05		12.0		dBm
	0.5		15.5		
	1.0		15.6		
Output Power @ 1 dB compression (2)	2.0		14.6		
,	3.0		15.2		
	4.0		13.8		
	5.0		16.0		
DO 0 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	6.0		15.8		1.00
DC Current Variation vs. Temperature (3)			-0.1		mA/°C
Thermal Resistance			128		°C/W

## Absolute Maximum Ratings(4)

- 110 0 0 1 0 1 1 0 1 1 1 1 1 1 1 1 1 1				
Parameter	Ratings			
Operating Temperature (5)	-40°C to 85°C			
Storage Temperature	-55°C to 100°C			
Channel Temperature	150°C			
DC Voltage (Pad 6)	6V			
Power Dissipation	500mW			
DC Current (Pad 6)	60mA			
Bias Current (Pad 7)	10mA			
Input Power	20dBm			

<sup>(</sup>i) Measured on Mini-Circuits Characterization test board TB-502+. See Characterization Test Circuit (Fig. 1) (2) P1dB specified with external current limiting of 30mA;

These maximum ratings are not intended for continuous normal operation. (5) Defined with reference to ground pad temperature.



P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs & shopping online see web site

For detailed performance specs IF/RF MICROWAVE COMPONENTS

Capable of higher P1dB at higher current (see Fig.2)

<sup>(</sup>Surrent at 85°C - Current at -45°C)/130

(Permanent damage may occur if any of these limits are exceeded.

#### **Characterization Test Circuit**

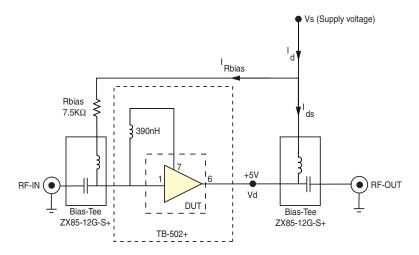
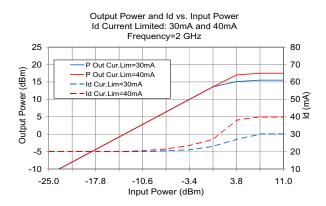


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization Test Board TB-502+) Gain, Output power at 1dB compression (P1dB), Output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X Microwave network analyzer.

#### Conditions:

- 1. Gain: Pin=-25 dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 5 dBm/tone at output.
- 3. Vs adjusted for 5V at device (Vd), compensating loss of bias tee.



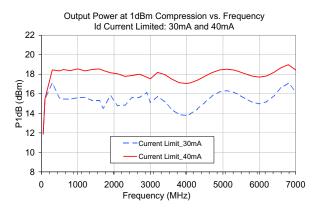


Fig 2. Output Power and Id vs. Input Power and Frequency. Performance measured on Mini-Circuits Characterization test board TB-502+. See Characterization Test Circuit (Fig. 1) Measurements performed with current (Id) limited as noted.

For detailed performance specs

## **Recommended Application Circuit**

(refer to evaluation board for PCB Layout and component values)

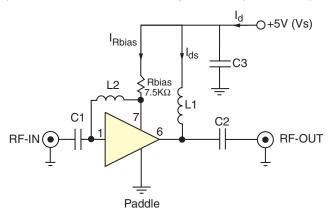


Fig 3. Recommended Application Circuit Note: Resistance of L1, 0.1-0.2 $\Omega$  typically

#### Typical Current (Id) as a function of Rbias (Vd = 5V)

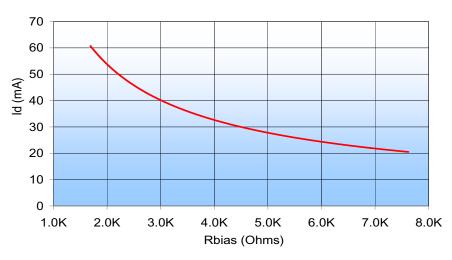
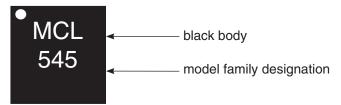


Fig 4. Id varies as a function of Rbias. The Id current range is defined based upon the specific Rbias value noted in the Application Circuit (Fig 3). Rbias may be adjusted to optimize Id for a customers' application. RF performance will vary accordingly.

## **Product Marking**



## **Additional Detailed Technical Information**

Additional information is available on our web site www.minicircuits.com. To access this information enter the model number on our web site home page.

Performance data, graphs, s-parameter data set (.zip file)

Case Style: DQ849

Plastic package, exposed paddle, lead finish: tin-silver nickel

Tape & Reel: F66

Suggested Layout for PCB Design: PL-299

Evaluation Board: TB-501-4+ (50-5000 MHz)

**Environmental Ratings: ENV08T1** 

#### **ESD Rating**

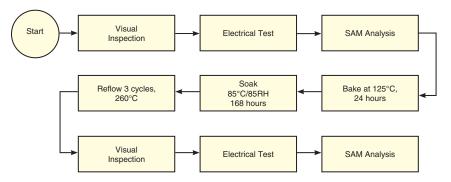
Human Body Model (HBM): Class 1A (250V to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (40V) in accordance with ANSI/ESD STM5.2-1999

## **MSL Rating**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

#### **MSL Test Flow Chart**



For detailed performance specs

P.O. Box 350166, Brooklyn, New York 11235-0003 (718) 934-4500 Fax (718) 332-4661 The Design Engineers Search Engine

Provides ACTUAL Data Instantly at minicipouits.com IF/RF MICROWAVE COMPONENTS